NSN 5961-01-150-1754

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-150-1754 **Inclosure Material:** Metal **Overall Length:** 0.740 inches **Terminal Length:** 0.250 inches **Overall Height:** Between 0.030 inches and 0.080 inches **Overall Width:** Between 0.300 inches and 0.330 inches **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 65.0 collector to base voltage, dc all transistor and 6.0 collector to emitter voltage, dc all transistor and 40.0 collector to emitter voltage/static/base open all transistor **Current Rating Per Characteristic:** 1.00 amperes source cutoff current all transistor **Power Rating Per Characteristic:** 600.0 milliwatts small-signal input power, common-collector preset all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: npn **Precious Material And Location:** Leads gold **Precious Material:** Gold **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure:**

No

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Demilitarization: